# 2SJ221

## Silicon P-Channel MOS FET

# **HITACHI**

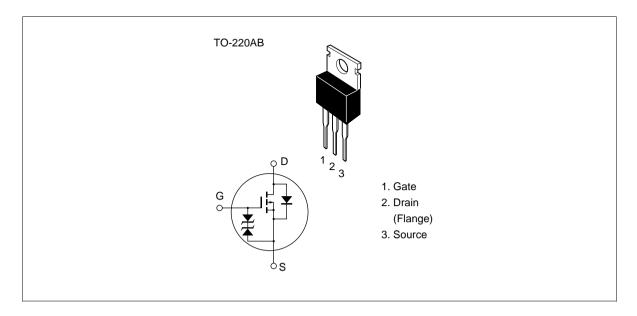
#### **Application**

High speed power switching

#### **Features**

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
  - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

#### **Outline**





## 2SJ221

## **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{ exttt{DSS}}$	-100	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	I <sub>D</sub>	-20	А
Drain peak current	I <sub>D(pulse)</sub> *1	-80	А
Body to drain diode reverse drain current	I <sub>DR</sub>	-20	А
Channel dissipation	Pch*2	75	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

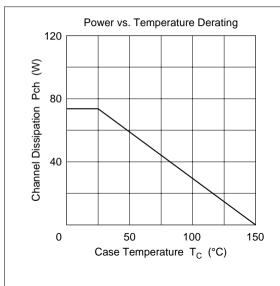
Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

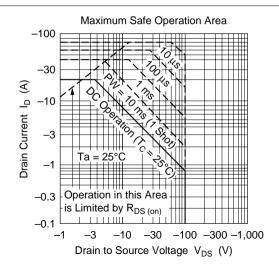
2. Value at  $T_c = 25^{\circ}C$ 

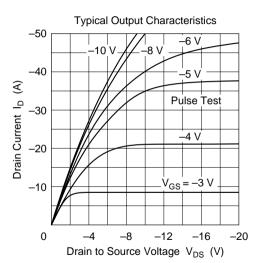
## **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

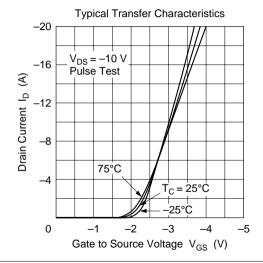
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-100	_	_	V	$I_{D} = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	-250	μΑ	$V_{DS} = -80 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{\rm GS(off)}$	-1.0	_	-2.0	V	$I_{D} = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state	$R_{\text{DS(on)}}$	_	0.12	0.16	Ω	$I_D = -10 \text{ A}, V_{GS} = -10 \text{ V}^{*1}$
resistance		_	0.16	0.22	_	$I_D = -10 \text{ A}, V_{GS} = -4 \text{ V}^{*1}$
Forward transfer admittance	y <sub>fs</sub>	7.5	12	_	S	$I_D = -10 \text{ A}, V_{DS} = -10 \text{ V}^{*1}$
Input capacitance	Ciss	_	1800	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	680	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	145	_	pF	_
Turn-on delay time	$t_{\text{d(on)}}$	_	15	_	ns	$I_D = -10 \text{ A}, V_{GS} = -10 \text{ V},$
Rise time	t <sub>r</sub>	_	115	_	ns	$R_L = 3 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	320	_	ns	_
Fall time	t <sub>f</sub>	_	170	_	ns	
Body to drain diode forward voltage	$V_{DF}$		-1.05		V	$I_F = -20 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>		280	_	ns	$I_F = -20 \text{ A}, V_{GS} = 0,$ $di_F/dt = 50 \text{ A}/\mu\text{s}$

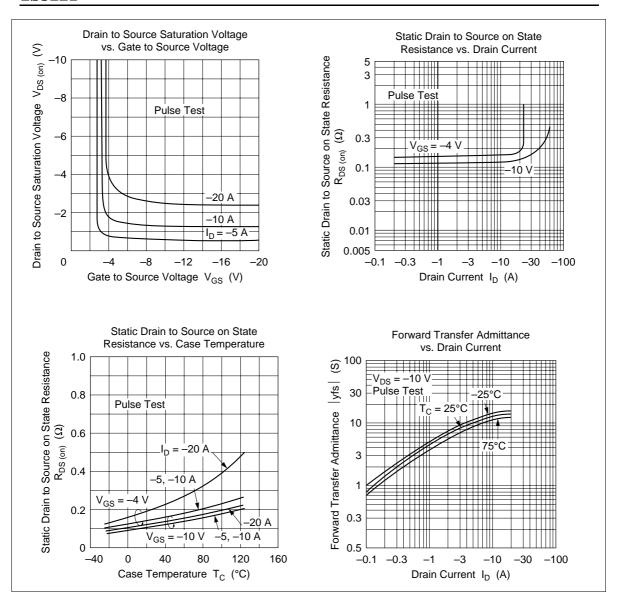
Note: 1. Pulse test

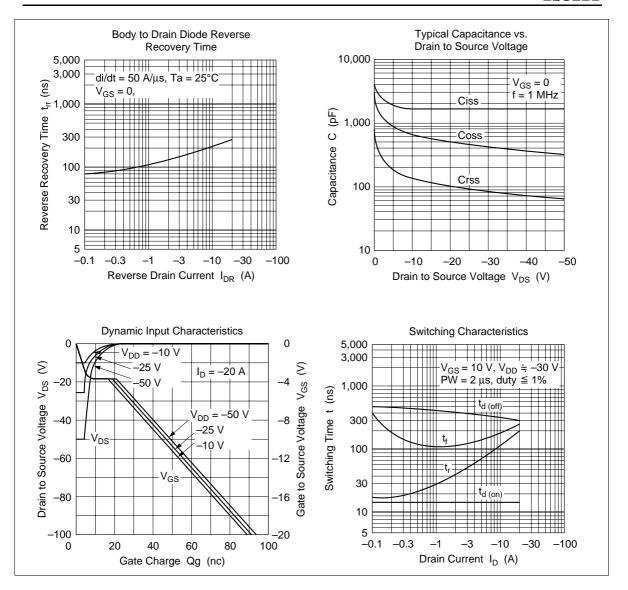


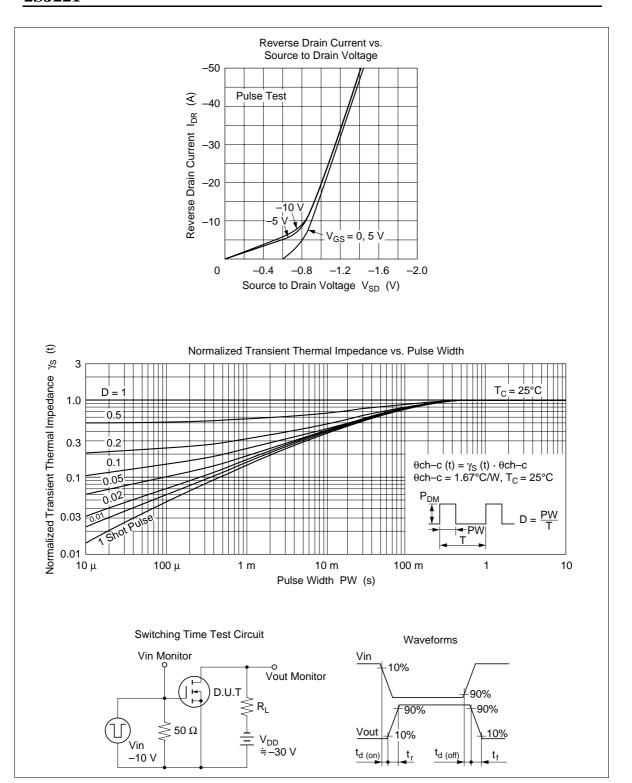




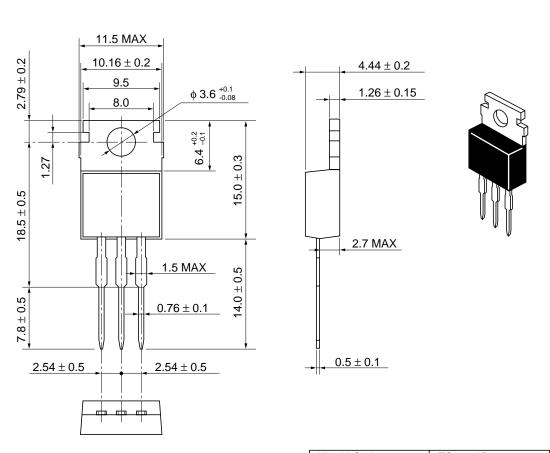








Unit: mm



Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.8 g

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